

KSP44/45

High Voltage Transistor

- Collector-Emitter Voltage: V_{CEO}=KSP44: 400V KSP45: 350V
- Collector Power Dissipation: P_C (max)=625mW



NPN Epitaxial Silicon Transistor

1. Emitter 2. Base 3. Collector

Absolute Maximum Ratings T_a=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage		
	: KSP44	500	V
	: KSP45	400	V
V _{CEO}	Collector-Emitter Voltage		
	: KSP44	400	V
	: KSP45	350	V
V _{EBO}	Emitter-Base Voltage	6	V
I _C	Collector Current	300	mA
P _C	Collector Power Dissipation (T _a =25°C)	625	mW
P _C	Collector Power Dissipation (T _C =25°C)	1.5	W
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

Electrical Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I _C =100μA, I _B =0			
	: KSP44		500		V
	: KSP45		400		V
BV _{CEO}	* Collector -Emitter Breakdown Voltage	I _C =1mA, I _B =0			
	: KSP44		400		V
	: KSP45		350		V
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E =100μA, I _C =0	6		V
I _{CBO}	Collector Cut-off Current				
	: KSP44	V _{CB} =400V, I _E =0		0.1	μΑ
	: KSP45	V _{CB} =320V, I _E =0		0.1	μΑ
I _{CES}	Collector Cut-off Current				
	: KSP44	V _{CE} =400V, I _B =0		0.5	μΑ
	: KSP45	V _{CE} =320V, I _B =0		0.5	μΑ
I _{EBO}	Emitter Cut-off Current	V _{EB} =4V, I _C =0		0.1	μΑ
h _{FE}	* DC Current Gain	V _{CE} =10V, I _C =1mA	40		
		V _{CE} =10V, I _C =10mA	50	200	
		V _{CE} =10V, I _C =50mA	45		
		V _{CE} =10V, I _C =100mA	40		
V _{CE} (sat)	* Collector-Emitter Saturation Voltage	I _C =1mA, I _B =0.1mA		0.4	V
		I _C =10mA, I _B =1mA		0.5	V
		I _C =50mA, I _B =5mA		0.75	V
V _{BE} (sat)	* Base-Emitter Saturation Voltage	I _C =10mA, I _B =1mA		0.75	V
C _{ob}	Output Capacitance	V _{CB} =20V, I _E =0, f=1MHz		7	pF

* Pulse Test: PW≤300μs, Duty Cycle≤2%

Typical Characteristics

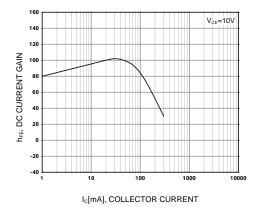


Figure 1. DC current Gain

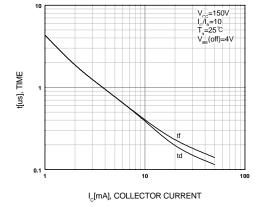


Figure 2. Turn-On Switching Times

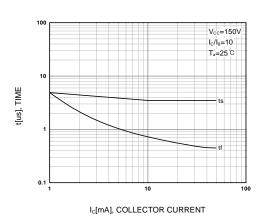


Figure 3. Turn-Off Switching Times

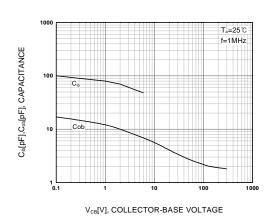


Figure 4. Capacitance

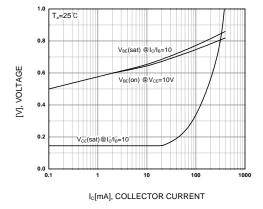


Figure 5. On Voltage

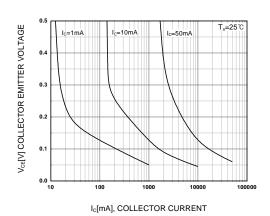


Figure 6. Collector Saturation Region

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Typical Characteristics (Continued)

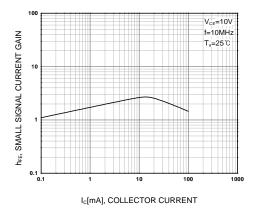


Figure 7. High Frequency Current Gain

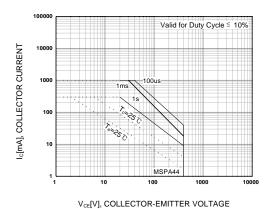
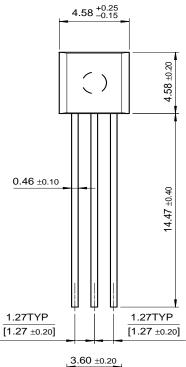
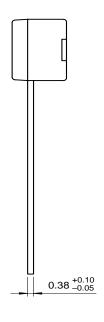


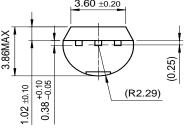
Figure 8. Safe Operating Area

Package Dimensions

TO-92







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